



DMN2710UFBQ

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on)	Ι _D T _A = +25°C
	0.45Ω @V _{GS} = 4.5V	1.3A
20V	0.6Ω @V _{GS} = 2.5V	1.2A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(ON)}$) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

Portable electronics

Features and Benefits

- Footprint of Just 0.6mm² 13 Times Smaller than SOT23
- Low Gate Threshold Voltage
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES[™] DMN2710UFBQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: X1-DFN1006-3
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.001 grams (Approximate)

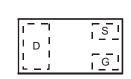


ESD PROTECTED



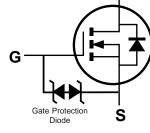
X1-DFN1006-3

Bottom View



Top View

Internal Schematic



D

Equivalent Circuit

Ordering Information (Note 4)

Part Number	Paakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMN2710UFBQ-7	X1-DFN1006-3	3,000	Tape & Reel	
DMN2710UFBQ-7B	X1-DFN1006-3	10,000	Tape & Reel	

Notes:

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BD = Product Type Marking Code

Top View Bar Denotes Gate and Source Side



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	20	V
Gate-Source Voltage			V _{GSS}	±6	V
Continuous Drain Current (Note 6) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	1.3 1.1	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			lдм	5	A
Maximum Body Diode Forward Current (Note 6)			ls	1.3	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.72	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	174	°C/W
Total Power Dissipation (Note 6)		PD	1.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	96	°C/W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	117	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Cumhal	Min	T	Max	Unit	Test Condition
	Symbol	MIN	Тур	wax	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	20	—		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current T _J = +25°C	IDSS		—	100	nA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	lgss	—		±1.0	μA	$V_{GS} = \pm 4.5 V$, $V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)			-		-	
Gate Threshold Voltage	VGS(TH)	0.5	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
		—	0.13	0.45	Ω	V _{GS} = 4.5V, I _D = 600mA
Static Drain-Source On-Resistance	RDS(ON)	_	0.17	0.6		$V_{GS} = 2.5V, I_D = 500mA$
		—	0.25	0.75		$V_{GS} = 1.8V, I_D = 350mA$
Diode Forward Voltage	Vsd		0.7	1.2	V	Vgs = 0V, Is = 150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	42	—	pF	
Output Capacitance	Coss	_	13	_	pF	VDS = 16V, VGS = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	6.5	_	pF	1 = 1.00012
Total Gate Charge	Qg	—	0.6	—	nC	
Gate-Source Charge	Qgs	_	0.1	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q _{gd}	_	0.1	_	nC	I _D = 250mA
Turn-On Delay Time	t _{D(ON)}	_	14	_	ns	
Turn-On Rise Time	tR	_	19	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	td(OFF)	_	57	_	ns	$R_{L} = 47\Omega, R_{g} = 10\Omega,$
Turn-Off Fall Time	tF	_	65		ns	$I_D = 200 \text{mA}$
Reverse Recovery Time	trr	_	88	_	ns	IF = 1A, di/dt = 100A/µs
Reverse Recovery Charge	QRR	_	29	—	nC	IF = 1A, di/dt = 100A/µs

Notes:

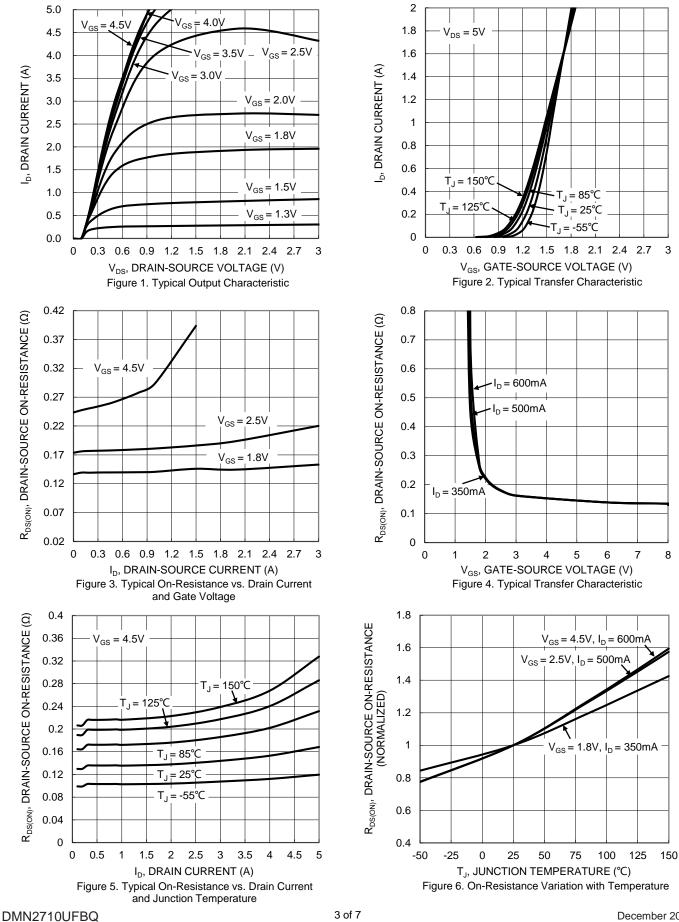
Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.

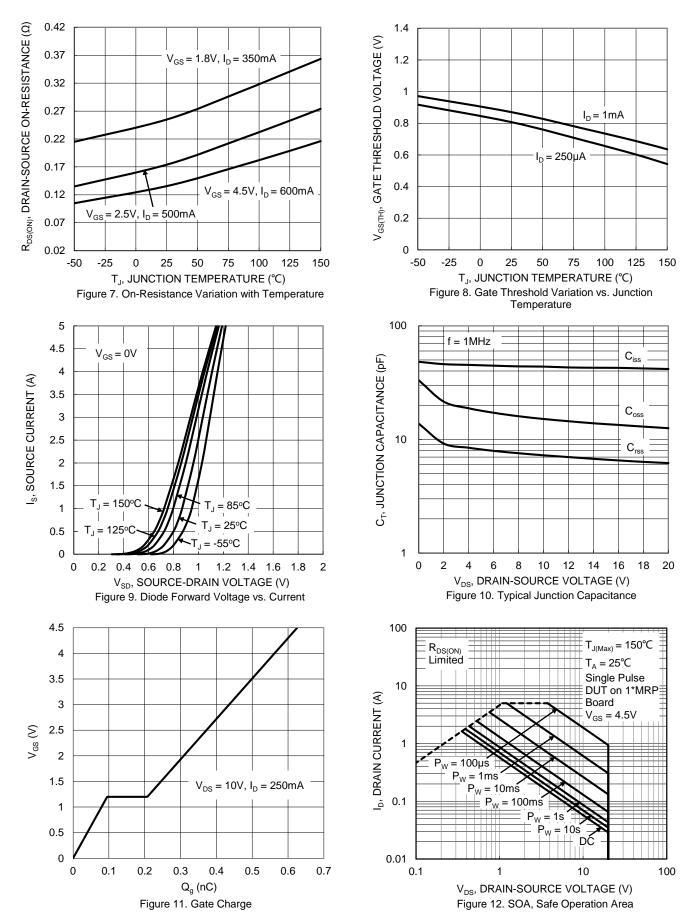


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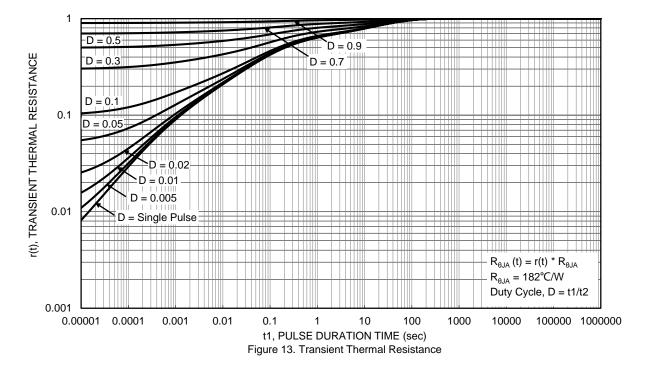
Document number: DS44521 Rev. 2 - 2





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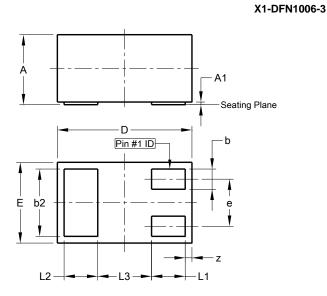






Package Outline Dimensions

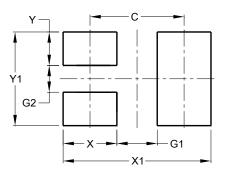
Please see http://www.diodes.com/package-outlines.html for the latest version.



Х	X1-DFN1006-3					
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
Е	0.55	0.675	0.60			
е	-	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
z	0.02	0.08	0.05			
All D	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X1-DFN1006-3

Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70



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